



PESD12VV1BL

Very low capacitance bidirectional ESD protection diode

Rev. 2 — 18 March 2013

Product data sheet

1. Product profile

1.1 General description

Very low capacitance bidirectional ElectroStatic Discharge (ESD) protection diode designed to protect one signal line from the damage caused by ESD and other transients. The device is housed in a leadless ultra small DFN1006-2 (SOD882) Surface-Mounted Device (SMD) plastic package.

1.2 Features and benefits

- Bidirectional ESD protection of one line
- Low diode capacitance $C_d = 17$ pF
- Rated peak pulse power: $P_{PPM} = 290$ W
- Ultra low leakage current $I_{RM} < 1$ nA
- ESD protection up to 30 kV
- IEC 61000-4-2; level 4 (ESD)
- IEC 61000-4-5 (surge); $I_{PPM} = 7.8$ A
- AEC-Q101 qualified

1.3 Applications

- Computers and peripherals
- Audio and video equipment
- Cellular handsets and accessories
- Portable electronics
- Communication systems

1.4 Quick reference data


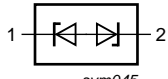
Table 1. Quick reference data

$T_{amb} = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{RWM}	reverse standoff voltage		-	-	12	V
C_d	diode capacitance	$f = 1$ MHz; $V_R = 0$ V	-	17	25	pF

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	cathode	 <p>Transparent top view</p>	 <p>sym045</p>
2	cathode		



3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PESD12VV1BL	DFN1006-2	leadless ultra small plastic package; 2 terminals; body 1.0 × 0.6 × 0.5 mm	SOD882

4. Marking

Table 4. Marking codes

Type number	Marking code
PESD12VV1BL	MW

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
P _{PPM}	rated peak pulse power		[1] -	290	W
I _{PPM}	rated peak pulse current	t _p = 8/20 μs	[1] -	7.8	A
T _j	junction temperature		-	150	°C
T _{amb}	ambient temperature		-55	+150	°C
T _{stg}	storage temperature		-65	+150	°C

[1] Device stressed with ten non-repetitive current pulses (8/20 μs exponential decay waveform according to IEC 61000-4-5 and IEC 61643-321).

Table 6. ESD maximum ratings

T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Max	Unit
V _{ESD}	electrostatic discharge voltage	IEC 61000-4-2 (contact discharge)	[1] -	30	kV
		machine model	-	400	V
		MIL-STD-883 (human body model)	-	10	kV

[1] Device stressed with ten non-repetitive ESD pulses.

Table 7. ESD standards compliance

Standard	Conditions
IEC 61000-4-2; level 4 (ESD)	> 15 kV (air); > 8 kV (contact)
MIL-STD-883; class 3B (human body model)	> 8 kV

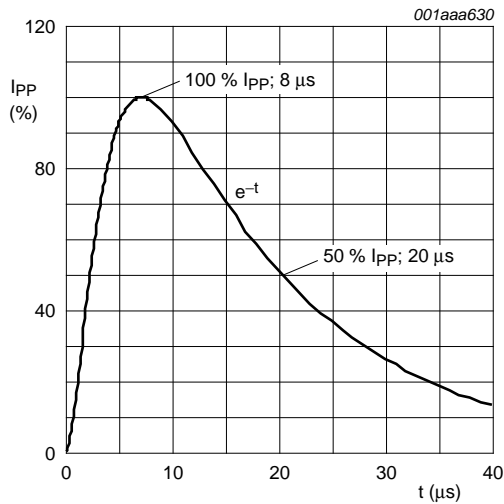


Fig 1. 8/20 μ s pulse waveform according to IEC 61000-4-5 and IEC 61643-321

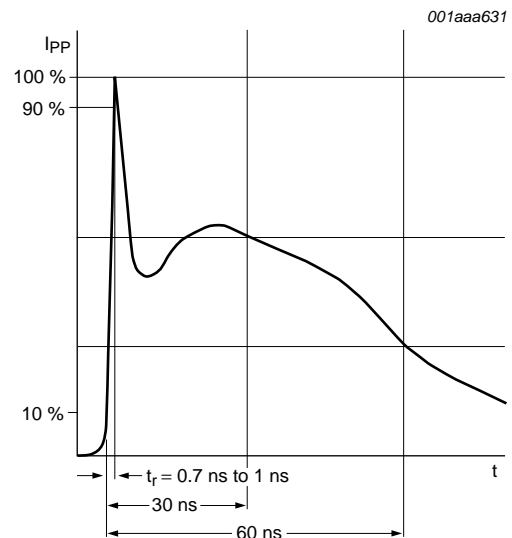


Fig 2. ESD pulse waveform according to IEC 61000-4-2

6. Characteristics

Table 8. Characteristics

$T_{amb} = 25^\circ\text{C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{RWM}	reverse standoff voltage		-	-	12	V
I_{RM}	reverse leakage current	$V_{RWM} = 12\text{ V}$	-	< 1	10	nA
V_{BR}	breakdown voltage	$I_R = 5\text{ mA}$	14.6	15.7	16.8	V
C_d	diode capacitance	$f = 1\text{ MHz}; V_R = 0\text{ V}$	-	17	25	pF
V_{CL}	clamping voltage	$I_{PP} = 1\text{ A}$	[1] -	-	22	V
		$I_{PPM} = 7.8\text{ A}$	[1] -	-	38	V
r_{dyn}	dynamic resistance	$I_R = 10\text{ A}$	[2] -	0.7	-	Ω

[1] Device stressed with 8/20 μ s exponential decay waveform according to IEC 61000-4-5 and IEC 61643-321.

[2] Non-repetitive current pulse, Transmission Line Pulse (TLP) $t_p = 100\text{ ns}$; square pulse; ANS/IESD STM5-1-2008.

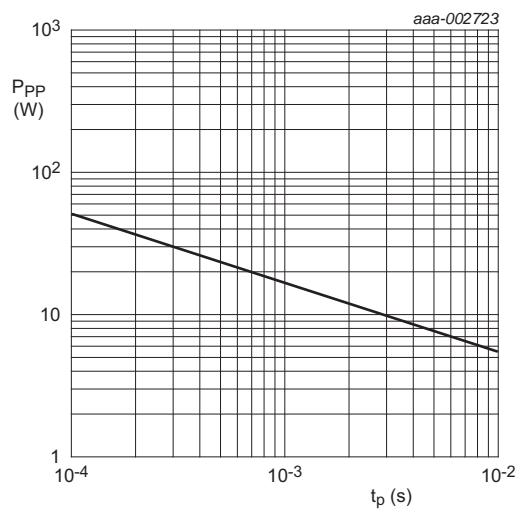


Fig 3. Rated peak pulse power as a function of square pulse duration; typical values

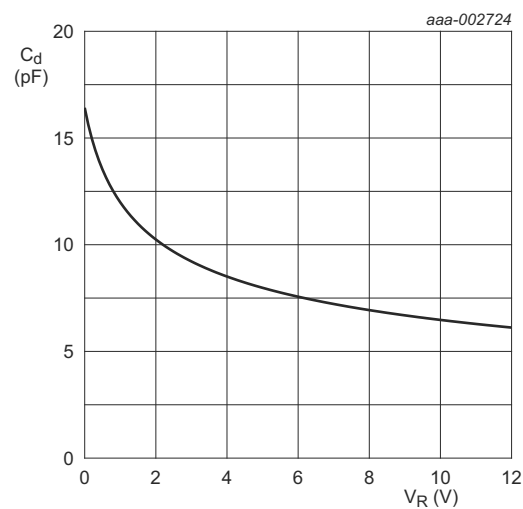


Fig 4. Diode capacitance as a function of reverse voltage; typical values

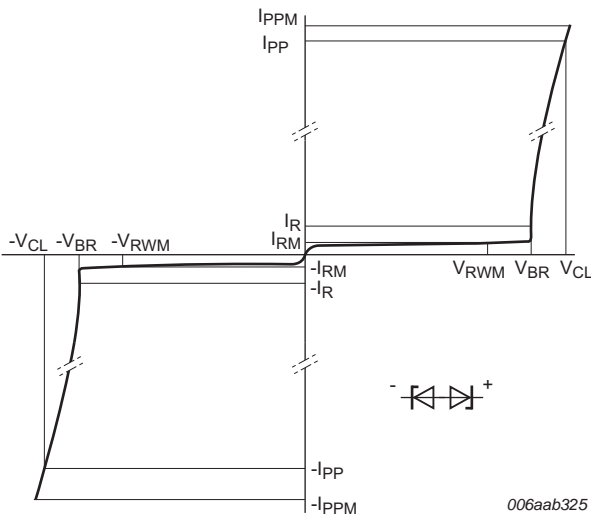


Fig 5. V-I characteristics for a bidirectional ESD protection diode

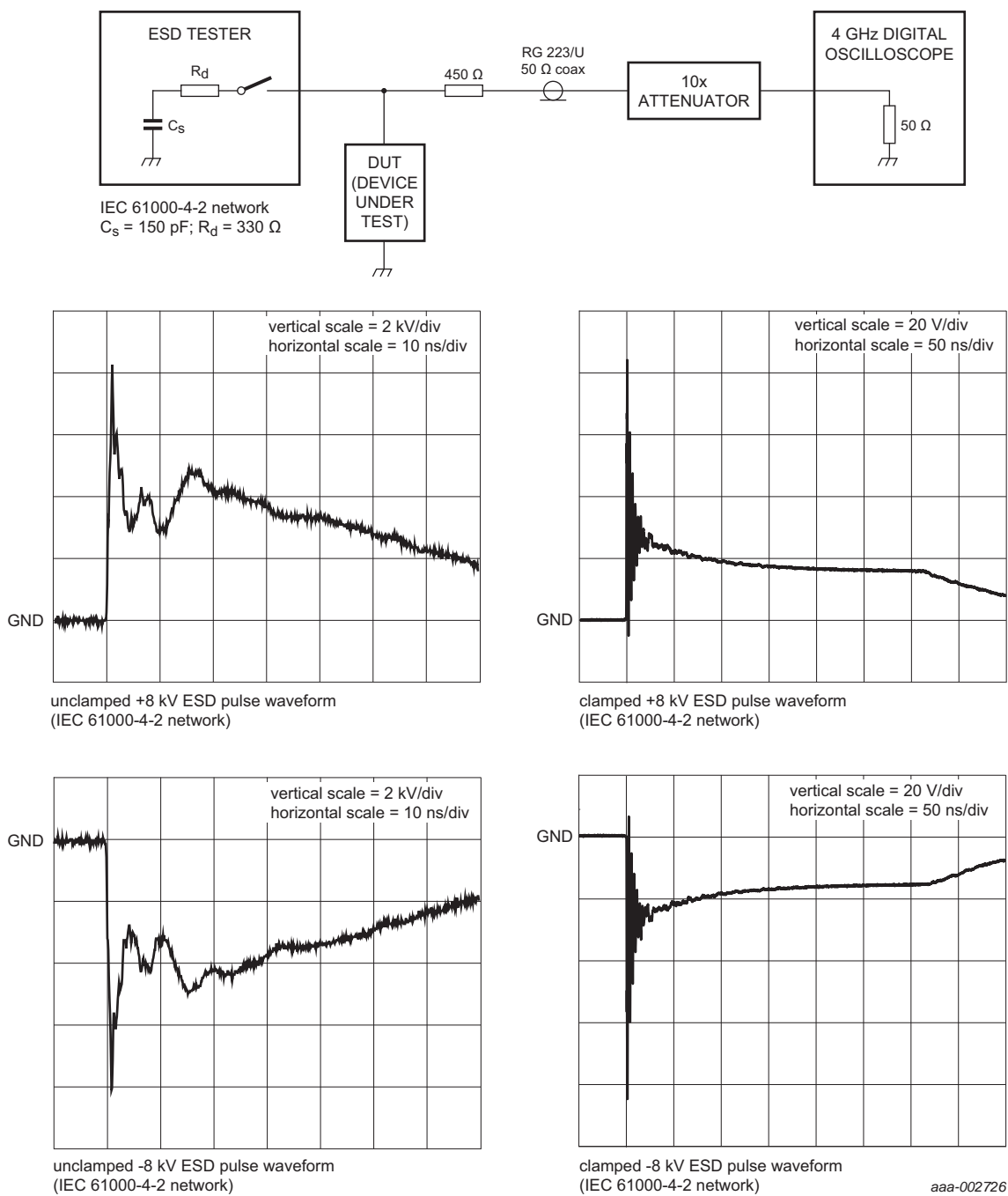


Fig 6. ESD clamping test setup and waveforms

7. Application information

The device is designed for the protection of one bidirectional data or signal line from surge pulses and ESD damage. The device is suitable on lines where the signal polarities are both, positive and negative with respect to ground.

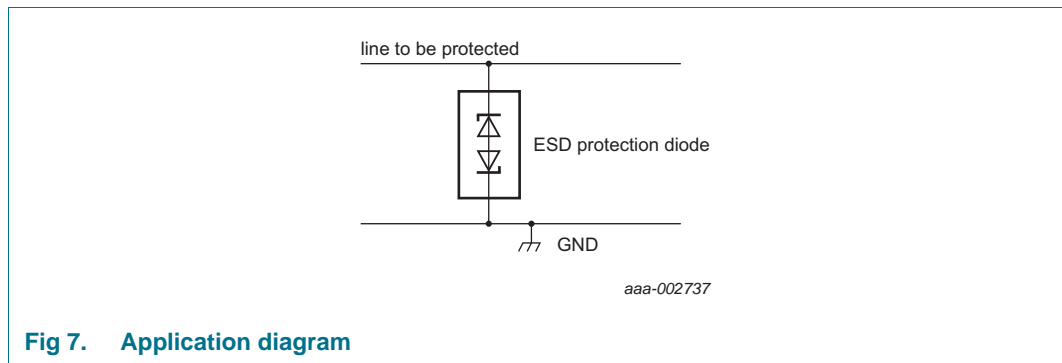


Fig 7. Application diagram

Circuit board layout and protection device placement

Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

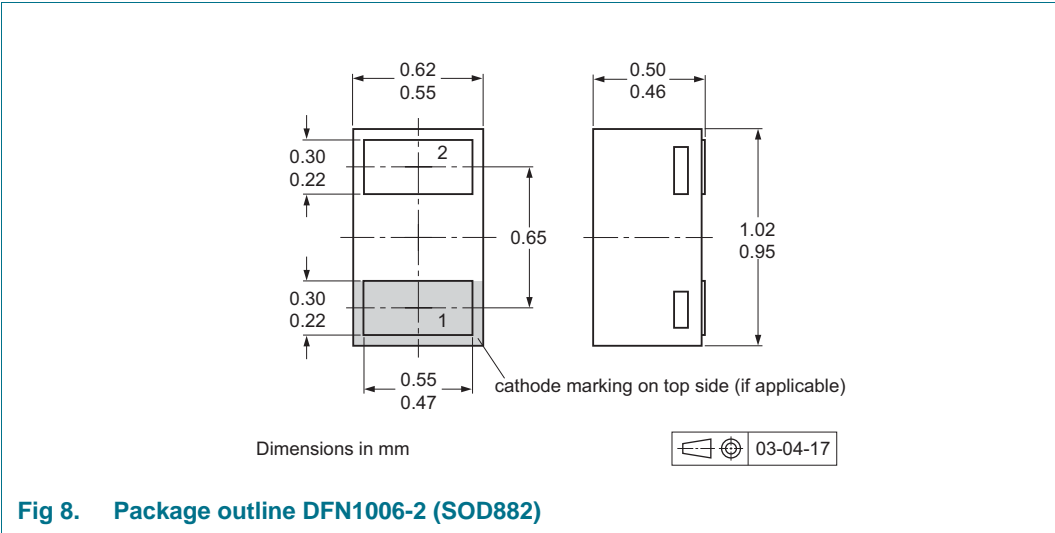
1. Place the device as close to the input terminal or connector as possible.
2. Minimize the path length between the device and the protected line.
3. Keep parallel signal paths to a minimum.
4. Avoid running protected conductors in parallel with unprotected conductors.
5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
6. Minimize the length of the transient return path to ground.
7. Avoid using shared transient return paths to a common ground point.
8. Use ground planes whenever possible. For multilayer PCBs, use ground vias.

8. Test information

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline

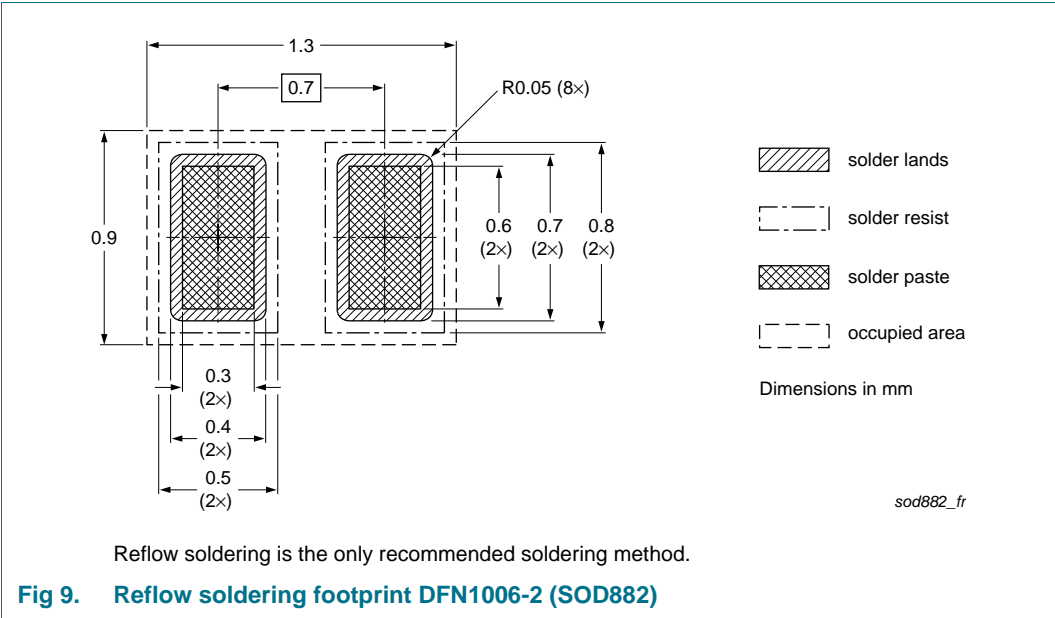


10. Packing information

Table 9. Packing methods			
The indicated -xxx are the last three digits of the 12NC ordering code. ^[1]			
Type number	Package	Description	Packing quantity
			10000
PESD12VV1BL	DFN1006-2 (SOD882)	4 mm pitch, 8 mm tape and reel	-315

[1] For further information and the availability of packing methods, see [Section 14](#).

11. Soldering



12. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PESD12VV1BL v.2	20130318	Product data sheet	-	PESD12VV1BL v.1
Modifications:	• Figure 3 corrected			
PESD12VV1BL v.1	20120403	Product data sheet	-	-

13. Legal information

13.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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